

## 1. General description

Planar passivated four quadrant triac in a SOT186A (TO-220F) "full pack" plastic package intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

## 2. Features and benefits

- High blocking voltage capability
- High noise immunity
- Isolated package
- Less sensitive gate for improved noise immunity
- Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants

## 3. Applications

- General purpose motor control
- General purpose switching

## 4. Quick reference data

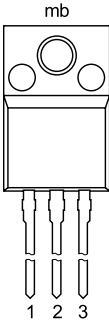
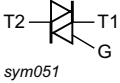
Table 1. Quick reference data

| Symbol                        | Parameter                            | Conditions  | Min | Typ | Max | Unit |
|-------------------------------|--------------------------------------|---|-----|-----|-----|------|
| $V_{DRM}$                     | repetitive peak off-state voltage    |   | -   | -   | 800 | V    |
| $I_{TSM}$                     | non-repetitive peak on-state current | full sine wave; $T_{j(\text{init})} = 25\text{ °C}$ ;<br>$t_p = 20\text{ ms}$ ; <a href="#">Fig. 4</a> ; <a href="#">Fig. 5</a> | -   | -   | 95  | A    |
| $T_j$                         | junction temperature                 |   | -   | -   | 125 | °C   |
| $I_{T(RMS)}$                  | RMS on-state current                 | full sine wave; $T_h \leq 56\text{ °C}$ ;<br><a href="#">Fig. 1</a> ; <a href="#">Fig. 2</a> ; <a href="#">Fig. 3</a>           | -   | -   | 12  | A    |
| <b>Static characteristics</b> |                                      |   |     |     |     |      |
| $I_{GT}$                      | gate trigger current                 | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2+ G+;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 7</a>                           | -   | 5   | 35  | mA   |
|                               |                                      | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2+ G-;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 7</a>                           | -   | 8   | 35  | mA   |
|                               |                                      | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2- G-;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 7</a>                           | -   | 10  | 35  | mA   |
|                               |                                      | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2- G+;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 7</a>                           | -   | 22  | 70  | mA   |

| Symbol                         | Parameter                         | Conditions  | Min | Typ | Max | Unit       |
|--------------------------------|-----------------------------------|---|-----|-----|-----|------------|
| <b>Dynamic characteristics</b> |                                   |   |     |     |     |            |
| $dV_D/dt$                      | rate of rise of off-state voltage | $V_{DM} = 536\text{ V}$ ; $T_j = 125\text{ °C}$ ; ( $V_{DM} = 67\%$ of $V_{DRM}$ ); exponential waveform; gate open circuit | 100 | 250 | -   | V/ $\mu$ s |

## 5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description             | Simplified outline   | Graphic symbol  |
|-----|--------|-------------------------|--|---|
| 1   | T1     | main terminal 1         |  |  |
| 2   | T2     | main terminal 2         |  |   |
| 3   | G      | gate                    |  |   |
| mb  | n.c.   | mounting base; isolated |  |   |

## 6. Ordering information

Table 3. Ordering information

| Type number | Package |   | Version |
|-------------|---------|---|---------|
|             | Name    | Description   |         |
| BT138X-800  | TO-220F | plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack" | SOT186A |

## 7. Marking

Table 4. Marking codes

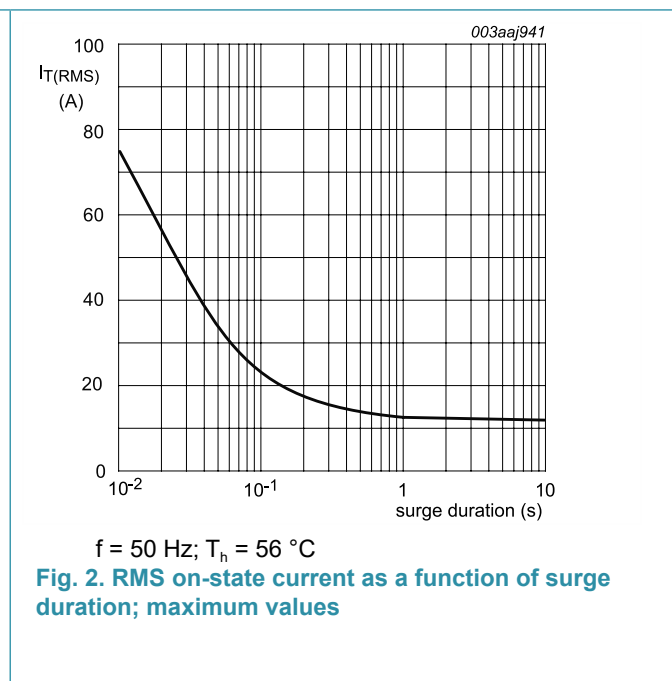
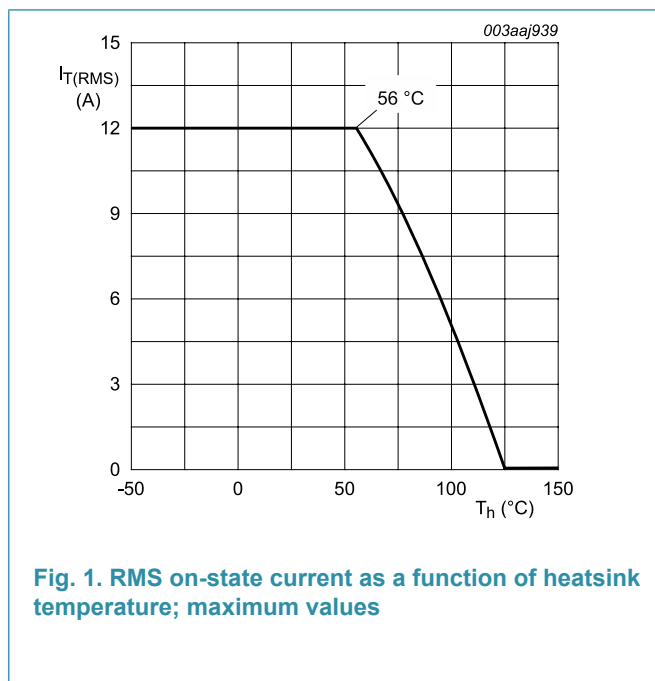
| Type number | Marking code |
|-------------|--------------|
| BT138X-800  | BT138X-800   |

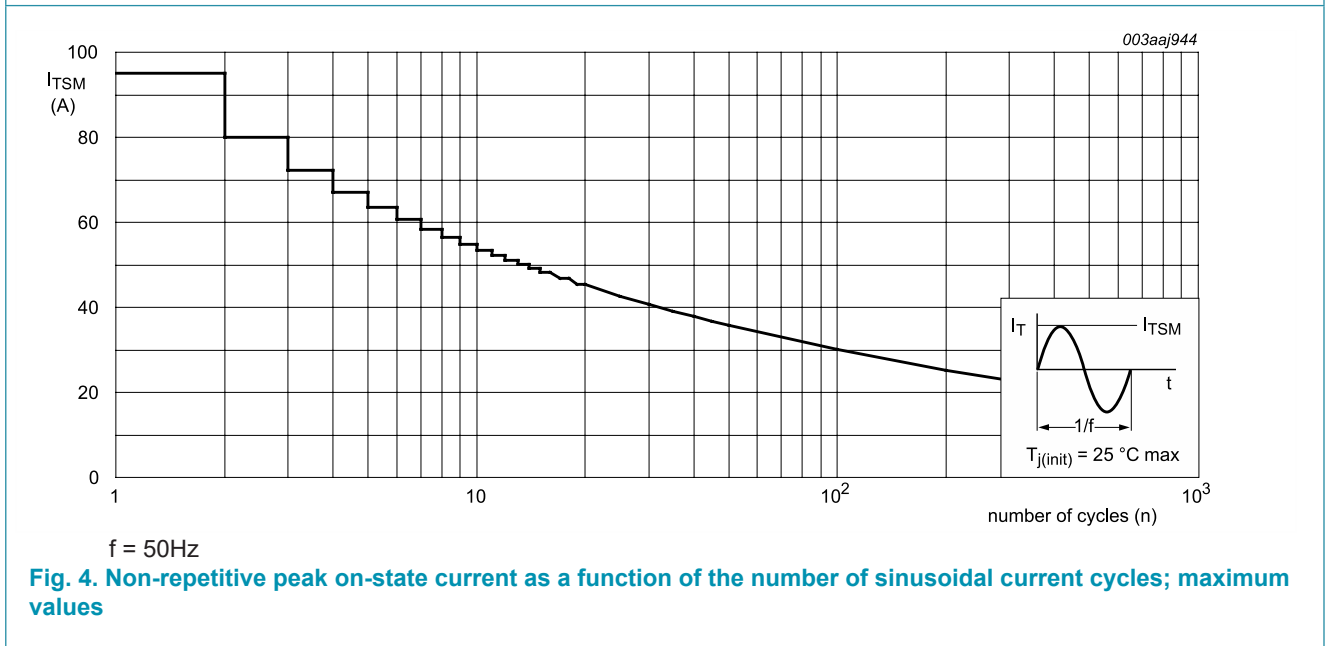
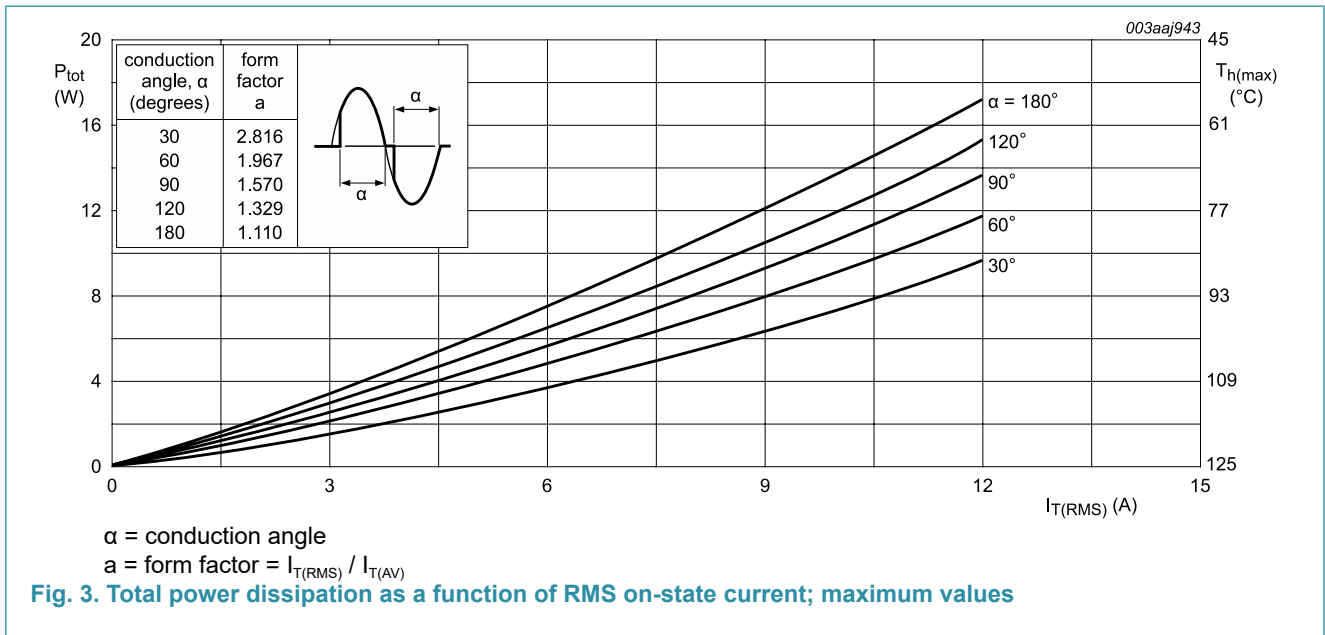
## 8. Limiting values

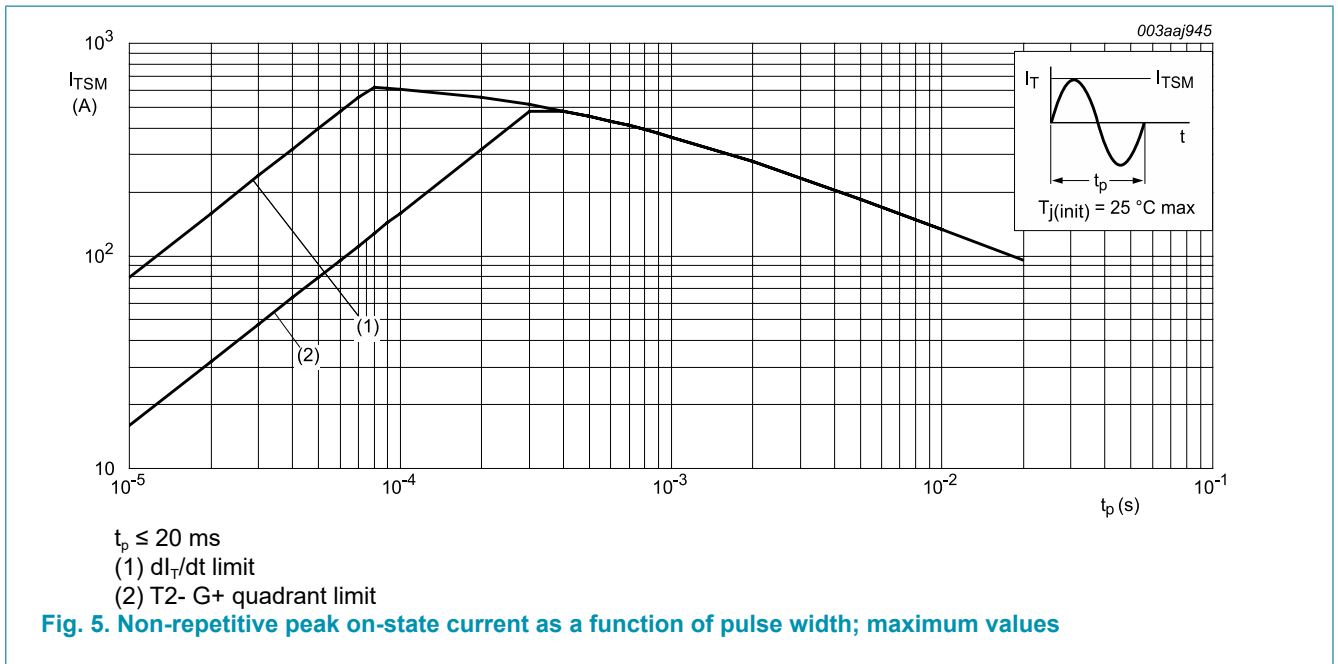
**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol       | Parameter                            | Conditions   | Min | Max | Unit        |
|--------------|--------------------------------------|--|-----|-----|-------------|
| $V_{DRM}$    | repetitive peak off-state voltage    |  | -   | 800 | V           |
| $I_{T(RMS)}$ | RMS on-state current                 | full sine wave; $T_h \leq 56\text{ °C}$ ;<br>Fig. 1; Fig. 2; Fig. 3                        | -   | 12  | A           |
| $I_{TSM}$    | non-repetitive peak on-state current | full sine wave; $T_{j(initial)} = 25\text{ °C}$ ;<br>$t_p = 20\text{ ms}$ ; Fig. 4; Fig. 5 | -   | 95  | A           |
|              |                                      | full sine wave; $T_{j(initial)} = 25\text{ °C}$ ;<br>$t_p = 16.7\text{ ms}$                | -   | 105 | A           |
| $I^2t$       | $I^2t$ for fusing                    | $t_p = 10\text{ ms}$ ; sine-wave pulse   | -   | 45  | $A^2s$      |
| $di_T/dt$    | rate of rise of on-state current     | $I_G = 70\text{ mA}$ ; T2+ G+  | -   | 50  | $A/\mu s$   |
|              |                                      | $I_G = 70\text{ mA}$ ; T2+ G-  | -   | 50  | $A/\mu s$   |
|              |                                      | $I_G = 70\text{ mA}$ ; T2- G-  | -   | 50  | $A/\mu s$   |
|              |                                      | $I_G = 140\text{ mA}$ ; T2- G+   | -   | 10  | $A/\mu s$   |
| $I_{GM}$     | peak gate current                    |  | -   | 2   | A           |
| $P_{GM}$     | peak gate power                      |  | -   | 5   | W           |
| $P_{G(AV)}$  | average gate power                   | over any 20 ms period  | -   | 0.5 | W           |
| $T_{stg}$    | storage temperature                  |  | -40 | 150 | $^{\circ}C$ |
| $T_j$        | junction temperature                 |  | -   | 125 | $^{\circ}C$ |



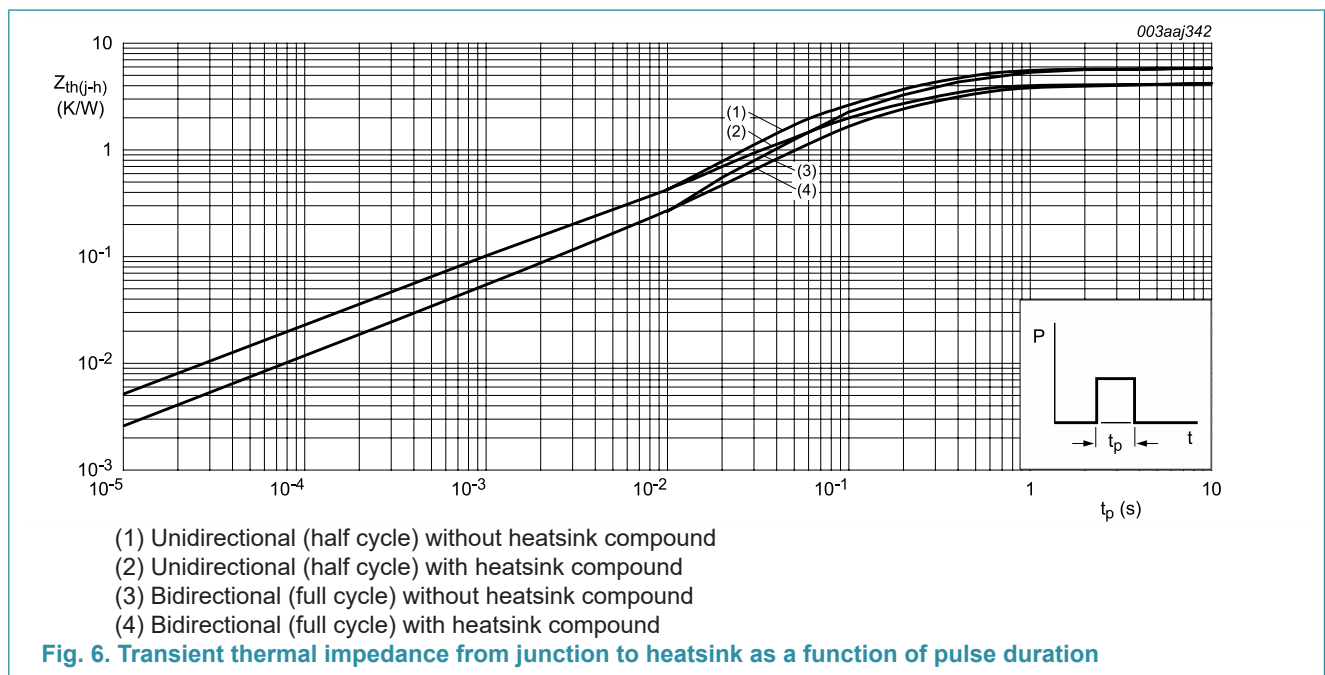




## 9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol        | Parameter                                    | Conditions  | Min | Typ | Max | Unit |
|---------------|--|---|-----|-----|-----|------|
| $R_{th(j-h)}$ | thermal resistance from junction to heatsink | full or half cycle; with heatsink compound; <a href="#">Fig. 6</a>    | -   | -   | 4   | K/W  |
|               |  | full or half cycle; without heatsink compound; <a href="#">Fig. 6</a> | -   | -   | 5.5 | K/W  |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient  | in free air   | -   | 55  | -   | K/W  |



## 10. Isolation characteristics

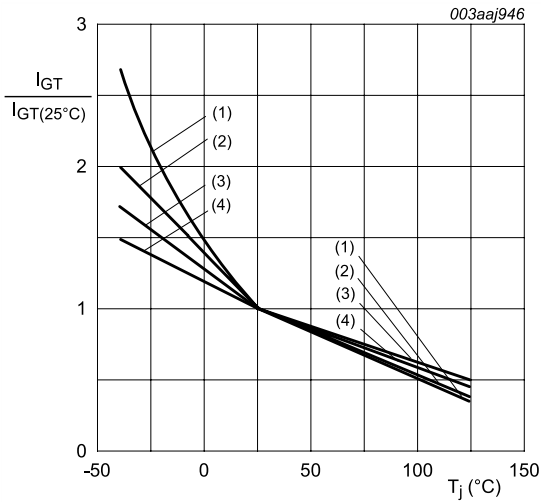
Table 7. Isolation characteristics

| Symbol          | Parameter             | Conditions   | Min | Typ | Max  | Unit |
|-----------------|-----------------------|--|-----|-----|------|------|
| $V_{isol(RMS)}$ | RMS isolation voltage | from all terminals to external heatsink; sinusoidal waveform; clean and dust free; $50\text{ Hz} \leq f \leq 60\text{ Hz}$ ; $RH \leq 65\%$ ; $T_h = 25\text{ }^\circ\text{C}$ | -   | -   | 2500 | V    |
| $C_{isol}$      | isolation capacitance | from main terminal 2 to external heatsink; $f = 1\text{ MHz}$ ; $T_h = 25\text{ }^\circ\text{C}$   | -   | 10  | -    | pF   |

## 11. Characteristics

Table 8. Characteristics

| Symbol                         | Parameter                         | Conditions  | Min  | Typ | Max  | Unit             |
|--------------------------------|-----------------------------------|---|------|-----|------|------------------|
| <b>Static characteristics</b>  |                                   |   |      |     |      |                  |
| $I_{GT}$                       | gate trigger current              | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2+ G+;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 7</a>                       | -    | 5   | 35   | mA               |
|                                |                                   | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2+ G-;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 7</a>                       | -    | 8   | 35   | mA               |
|                                |                                   | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2- G-;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 7</a>                       | -    | 10  | 35   | mA               |
|                                |                                   | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2- G+;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 7</a>                       | -    | 22  | 70   | mA               |
| $I_L$                          | latching current                  | $V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; T2+ G+;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 8</a>                       | -    | 7   | 40   | $\mu\text{A}$    |
|                                |                                   | $V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; T2+ G-;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 8</a>                       | -    | 20  | 60   | mA               |
|                                |                                   | $V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; T2- G-;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 8</a>                       | -    | 8   | 40   | mA               |
|                                |                                   | $V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; T2- G+;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 8</a>                       | -    | 10  | 60   | mA               |
| $I_H$                          | holding current                   | $V_D = 12\text{ V}$ ; $T_j = 25\text{ °C}$ ; <a href="#">Fig. 9</a>   | -    | 6   | 30   | mA               |
| $V_T$                          | on-state voltage                  | $I_T = 15\text{ A}$ ; $T_j = 25\text{ °C}$ ; <a href="#">Fig. 10</a>  | -    | 1.4 | 1.65 | V                |
| $V_{GT}$                       | gate trigger voltage              | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; $T_j = 25\text{ °C}$ ;<br><a href="#">Fig. 11</a>                              | -    | 0.7 | 1    | V                |
|                                |                                   | $V_D = 400\text{ V}$ ; $I_T = 0.1\text{ A}$ ; $T_j = 125\text{ °C}$ ;<br><a href="#">Fig. 11</a>                            | 0.25 | 0.4 | -    | V                |
| $I_D$                          | off-state current                 | $V_D = 800\text{ V}$ ; $T_j = 125\text{ °C}$  | -    | 0.1 | 0.5  | mA               |
| <b>Dynamic characteristics</b> |                                   |   |      |     |      |                  |
| $dV_D/dt$                      | rate of rise of off-state voltage | $V_{DM} = 536\text{ V}$ ; $T_j = 125\text{ °C}$ ; ( $V_{DM} = 67\%$ of $V_{DRM}$ ); exponential waveform; gate open circuit | 100  | 250 | -    | V/ $\mu\text{s}$ |
| $t_{gt}$                       | gate-controlled turn-on time      | $I_{TM} = 16\text{ A}$ ; $V_D = 800\text{ V}$ ; $I_G = 0.1\text{ A}$ ; $dI_G/dt = 5\text{ A}/\mu\text{s}$                   | -    | 2   | -    | $\mu\text{s}$    |



- (1) T2- G+
- (2) T2- G-
- (3) T2+ G-
- (4) T2+ G+

Fig. 7. Normalized gate trigger current as a function of junction temperature

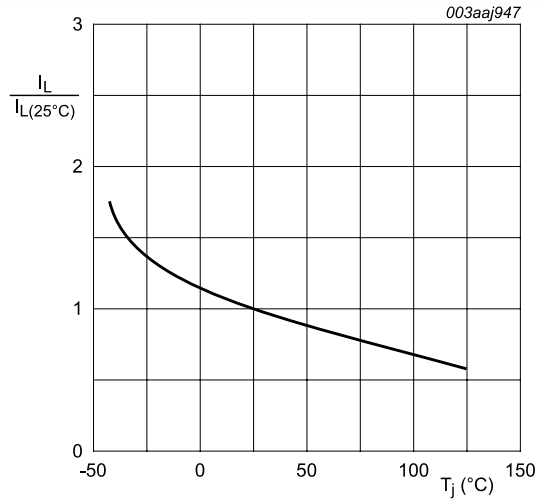


Fig. 8. Normalized latching current as a function of junction temperature

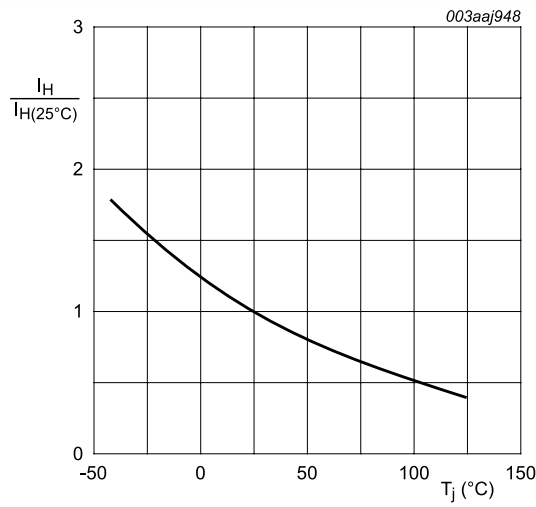
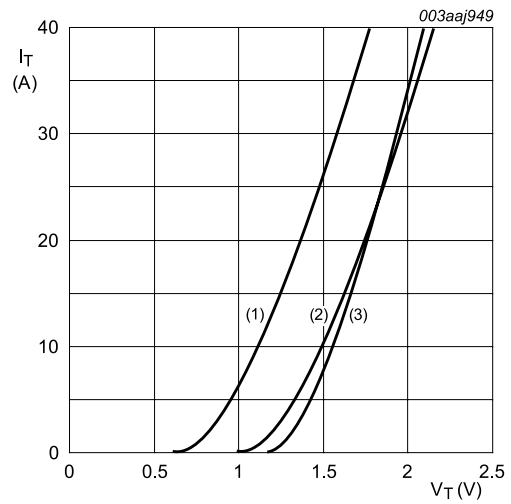


Fig. 9. Normalized holding current as a function of junction temperature



$V_o = 1.145 \text{ V}; R_s = 0.031 \Omega$

- (1)  $T_j = 125 \text{ }^\circ\text{C}$ ; typical values
- (2)  $T_j = 125 \text{ }^\circ\text{C}$ ; maximum values
- (3)  $T_j = 25 \text{ }^\circ\text{C}$ ; maximum values

Fig. 10. On-state current as a function of on-state voltage



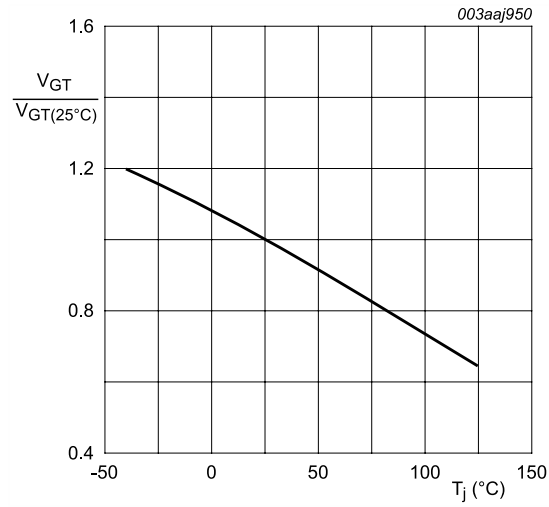
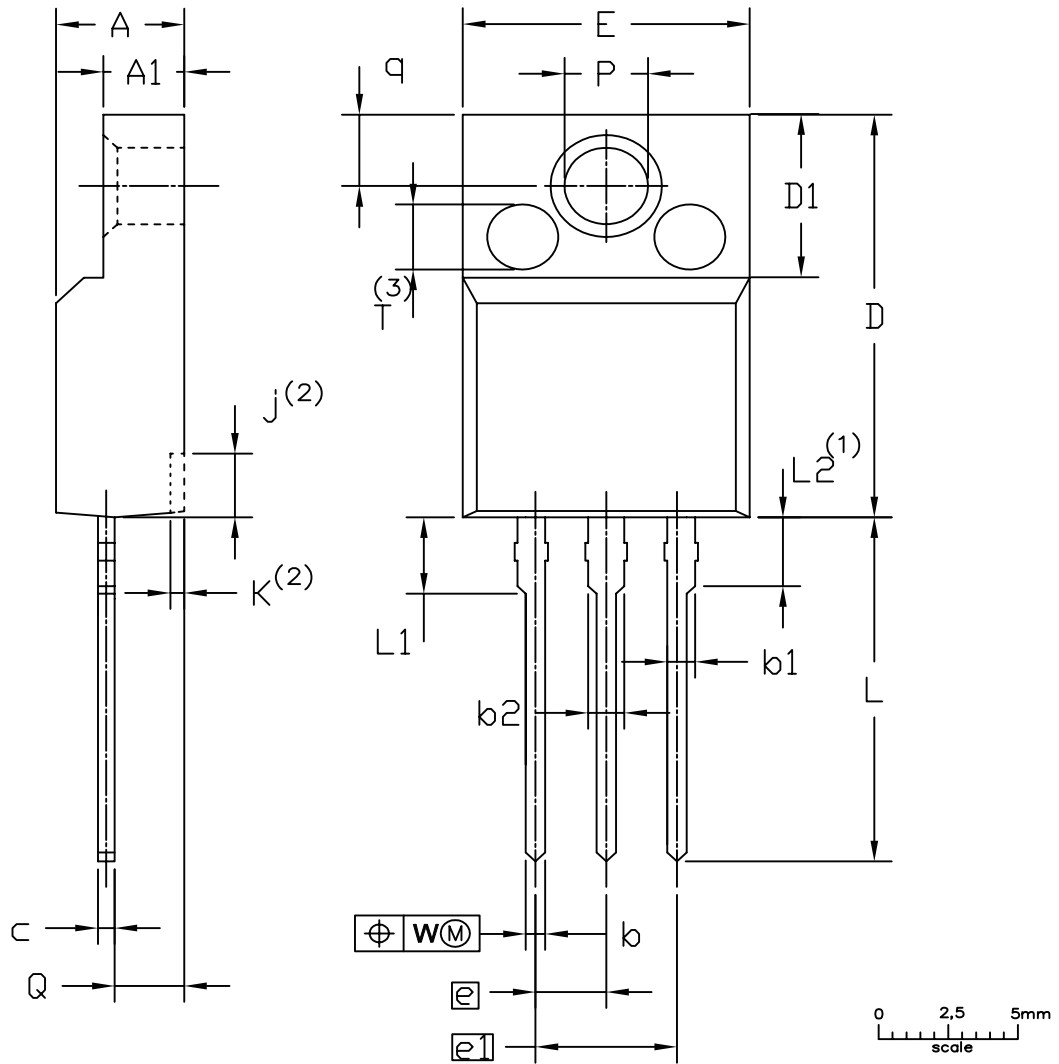


Fig. 11. Normalized gate trigger voltage as a function of junction temperature

## 12. Package outline

Plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"

SOT186A



| UNIT | A   | A <sub>1</sub> | b   | b <sub>1</sub> | b <sub>2</sub> | c   | D    | D <sub>1</sub> | E    | e    | e <sub>1</sub> | j <sup>(2)</sup> | k <sup>(2)</sup> | L    | L <sub>1</sub> | L <sub>2</sub> <sup>(1)</sup><br>max. | P   | Q   | q   | W   | T <sup>(3)</sup> |
|------|-----|----------------|-----|----------------|----------------|-----|------|----------------|------|------|----------------|------------------|------------------|------|----------------|---------------------------------------|-----|-----|-----|-----|------------------|
| mm   | 4.6 | 2.9            | 0.9 | 1.1            | 1.4            | 0.7 | 15.8 | 6.5            | 10.3 |      |                | 2.7              | 0.6              | 14.4 | 3.30           |                                       | 3.2 | 2.6 | 3.0 | 0.4 | 2.5              |
|      | 4.0 | 2.5            | 0.7 | 0.9            | 1.0            | 0.4 | 15.2 | 6.3            | 9.7  | 2.54 | 5.08           | 1.7              | 0.4              | 13.5 | 2.79           | 3                                     | 3.0 | 2.3 | 2.6 |     |                  |

**Notes**

- Terminal dimensions within this zone are uncontrolled
- Dot lines area designs may vary
- Eject pin mark is for reference only

| OUTLINE VERSION | REFERENCES |                |       | EUROPEAN PROJECTION | ISSUE DATE |
|-----------------|------------|----------------|-------|---------------------|------------|
|                 | IEC        | JEDEC          | JEITA |                     |            |
| SOT186A         |            | 3 LEADS TO220F |       |                     | 2013-11-14 |

## 13. Legal information

### Data sheet status

| Document status [1][2]         | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Date of release: 6 August 2018

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- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



## JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,  
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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